

MAINTENANCE MANUAL 406-512 MHz EXCITER BOARD 19D423346G1, G2

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DESCRIPTION

The exciter uses eight transistors, a crystal module and an integrated circuit to provide 200 milliwatts of RF drive to the PA assembly. The crystal module determines the (F1) transmitting frequency in single frequency applications. The exciter also contains the voltage compensation circuits and provides temperature compensation voltage to all crystal modules.

In multi-frequency transmitters, the crystal modules for frequencies F2-F4 are located on the multi-frequency board. In station applications requiring a frequency stability of 0.0002%, Integrated Circuit Oscillator Modules (ICOMs) are used. All ICOMs (F1-F4) are located on the multi-frequency board. In these applications the F1 oscillator (Q181) on the exciter board is not used.

The crystal frequency ranges from approximately 11.3 to 14.2 megahertz, and is multiplied 36 times.

Audio, supply voltages and control functions are connected from the system-audio & squelch board (SAS) to the exciter board through P902.

Centralized metering jack J103 is used with GE Test Set Model 4EX3A11 or Test Kit 4EX8K12. The Test Set meters the frequency multipliers, amplifier and measures the relative power out.

CIRCUIT ANALYSIS

F1 OSCILLATOR CIRCUIT

A Colpitts oscillator comprised of Q181, a plug-in crystal module and associated components provides the fundamental operating

frequency for the transmitter. The crystal module in the base circuit of Q181 is temperature compensated to maintain frequency stability within ± 5 PPM over a ambient temperature range of $-30\,^{\circ}\mathrm{C}$ to $+60\,^{\circ}\mathrm{C}$. Compensation voltage from compensator circuit Q182 is applied to the crystal module. The output of the oscillator is taken from the collector of Q181 and applied to the input of buffer Q101.

- SERVICE NOTE -

Yl and C2 on the crystal modules are not field replaceable items. C2 is factory selected to compliment the temperature/frequency characteristics of each individual crystal. Should it become necessary to replace either Yl or C2, the entire crystal module must be replaced.

In single frequency radios, the Fl keying lead is connected directly to A- by a DA jumper connected between H12 and H31 on the SAS board. This assures Fl oscillator operation each time the PTT switch is pressed.

With the radio turned on and the PTT switch operated, +10 Volts is present on the transmitter oscillator lead at P902-1 and the emitter of Q181. R182 and R183 comprise a voltage divider network to establish the base voltage for Q181, allowing it to oscillate at the crystal frequency.to allow F1 frequency selection via the frequency selector switch on the control unit.

When frequencies F2 thru F4 are selected the oscillator output frequency from the multi-frequency board is supplied to buffer Q101 through J102-1 on the exciter and cable W2601.

COMPENSATOR CIRCUITS

The crystal modules are temperature compensated at both ends of the temperature

range to provide instant frequency compensation. The temperature compensator consists of Q182, VR101, RT181, RT192 and associated components. Zener diode VR101 provides a constant +8.5 V reference voltage for compensator Q101.

The cold end compensation circuit does not operate at temperatures above $-10\,^{\circ}\mathrm{C}$ (+14 $^{\circ}\mathrm{F}$). When the temperature drops below $-10\,^{\circ}\mathrm{C}$, the circuit is activated. As the temperature decreases, the resistance of RT181 increases and the compensation voltage increases.

An increase in compensation voltage decreases the capacitance of the varactor in the oscillator, thereby increasing the output frequency of the crystal module.

The hot end compensation circuit does not operate at temperatures below $50\,^{\circ}\mathrm{C}$ ($122\,^{\circ}\mathrm{F}$). When the temperature rises above $+50\,^{\circ}\mathrm{C}$, the circuit is activated. As the temperature increases, the resistance of RT192 decreases and the compensation voltage decreases. The decrease in compensation voltage increases the capacity of the varactor, decreasing the output frequency of the crystal module.

Listed below are typical minimum and maximum voltage readings to be expected at pin 4 of the crystal modules. Voltages should be measured using a high impedance meter.

TEMPERATURE	OUTPUT VOLTAGE		
RANGE	MINIMUM	MAXIMUM	
-30°C -10° to 50°C +75°C	4.9 Volts 3.7 Volts 3.3 Volts	6.0 Volts 4.3 Volts 3.8 Volts	

AUDIO IC

The transmitter audio circuitry is contained in audio IC U101. A simplified drawing of the audio IC is shown in Figure 1.

Audio from the microphone at pin 12 is coupled through pre-emphasis capacitor C1 to the base of Q1 in the operational amplifier-limiter circuit. Collector voltage for the transistorized microphone preamplifier is supplied from the 10-Volt regulator through R980 & R979 on the System-Audio-Squelch board to J901A-14 in MASTR Executive II radios.

In Custom MVP radios, collector voltage for the transistorized microphone preamplifier is supplied from the 20-Volt regulator on the SAS board through R928, R929 and J913 to the microphone.

The operational amplifier-limiter circuit consists of Q1, Q2 and Q3. Q3 provides limiting at high signal levels. The gain of the operational amplifier circuit is fixed by negative feedback through R19, R20 and the resistance in the network (Pin 9).

The output of Q3 is coupled through a de-emphasis network (R10 and C3) to an active post-limiter filter consisting of C4, C5, C6, R11, R12, R13, R15, R17 and Q4.

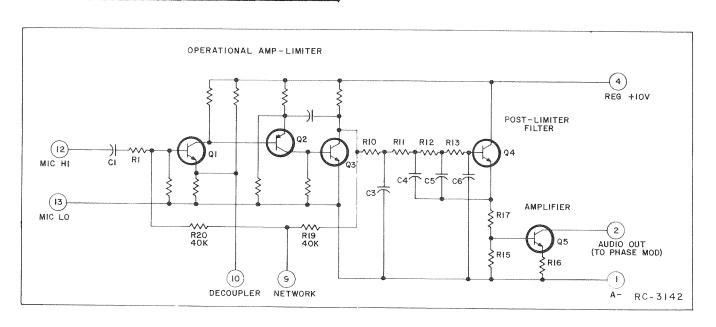


Figure 1 - Simplified Audio IC

Following the post-limiter filter is class A amplifier Q5. The output of Q5 is coupled through MOD ADJUST potentiometer R104 and resistor R109 to the phase modulator.

- SERVICE NOTE -

If the DC voltages applied to the audio IC are correct and there is no audio output, replace UlO1. For radios equipped with Channel Guard, tone from the encoder is applied to the phase modulator through P902-9, (CG H1) and resistor R113. Refer to the Transmitter Alignment procedures for Channel Guard modulation adjustment instructions.

BUFFER & PHASE MODULATOR

The oscillator output present at J102-1 (FL-F4) is coupled through buffer-amplifier Q101 to the modulator. The phase modulator, varactor (voltage-variable capacitor) CR180, is connected in series with tunable coil T101. This network appears as a series-resonant circuit to the RF output of the oscillator. An audio signal applied to the modulator circuit through blocking capacitor C109 varies the bias of CR180, resulting in a phase modulated output. A voltage divider network (R106 and R112) provides the proper operating bias for CR180.

The output of the modulator is coupled through blocking capacitor Cl16 to the base of buffer Q102. Cl16 and Cl17 also provide impedance matching between the modulator and buffer Q102.

MULTIPLIERS & AMPLIFIER

Buffer Q102 is saturated when no RF signal is present. Applying an RF signal to Q102 provides a sawtooth waveform at its

collector to drive class C tripler, Q103. The first tripler stage is metered through R117. The output of Q103 is coupled through tuned circuits T102, T103 and T104 to the base of the second tripler, Q104. T102, T103 and T104 are tuned to three times the crystal frequency. The second tripler stage, Q104, is metered through R122.

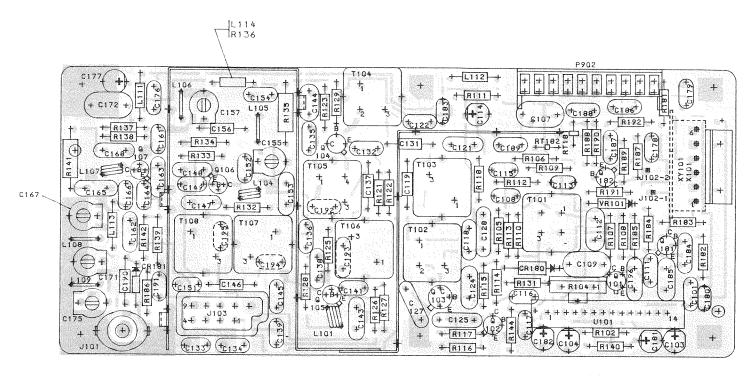
The output of Q104 is coupled through tuned circuits T105 and T106 to the base of first doubler Q105. T105 and T106 are tuned to nine times the crystal frequency. Q105 is metered through R126.

The output of Q105 is coupled through two tuned circuits (T107 and T108) to the base of second doubler Q106. These circuits are tuned to 18 times the crystal frequency (one-half the transmitter operating frequency). Q106 is metered through R133.

The output of Q106 is coupled to the base of power amplifier Q107 through impedance matching networks composed of C152. C155, L105, C156, C157, L106, and C161. These networks are all tuned to the operating frequency and present a high shunt impedance at the operating frequency. All other frequencies are shunted to ground. Q107 is metered through R142.

The output of Q107 is matched to 50 ohms by impedance matching network C166, C167, L108, L117, C171, L109 and C175. C167, C171, and C175 are tuned to the proper resonant frequency.

The exciter provides a minimum of 200 milliwatts of RF power to the power amplifier through J101 and cable W216. The relative output power of the exciter is metered by coupling through C190, detecting with CR181, and filtering with R186 and C191.



LEAB IDENTIFICATION FOR Q101-Q107,Q181,& Q182

C FLAT B

C E

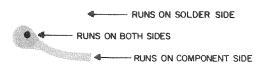
B CR

TRIANGULAR

TOP VIEW

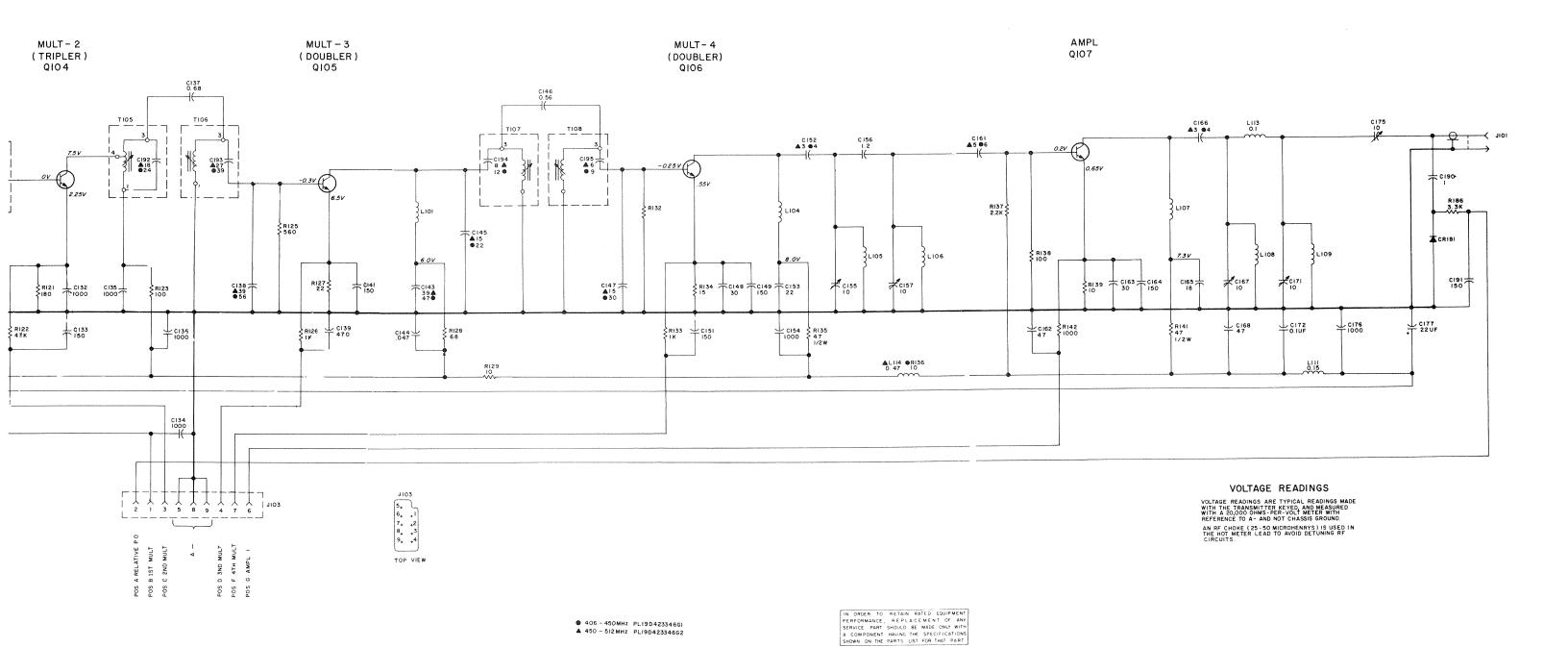
NOTE: LEAD ARRANGEMENT, AND NOT CASE SHAPE, IS DETERMINING FACTOR FOR LEAD IDENTIFICATION.

(19C327178, Rev. 6) (19B232260, Sh. 1, Rev. 2) (19B232260, Sh. 2, Rev. 1)



OUTLINE DIAGRAM

406—512 MHZ EXCITER BOARD 19D423346G1, 2



 EXCITER BOARD
 REV LETTER
 FREQ RANGE

 19D42334661
 D
 406-450MHz

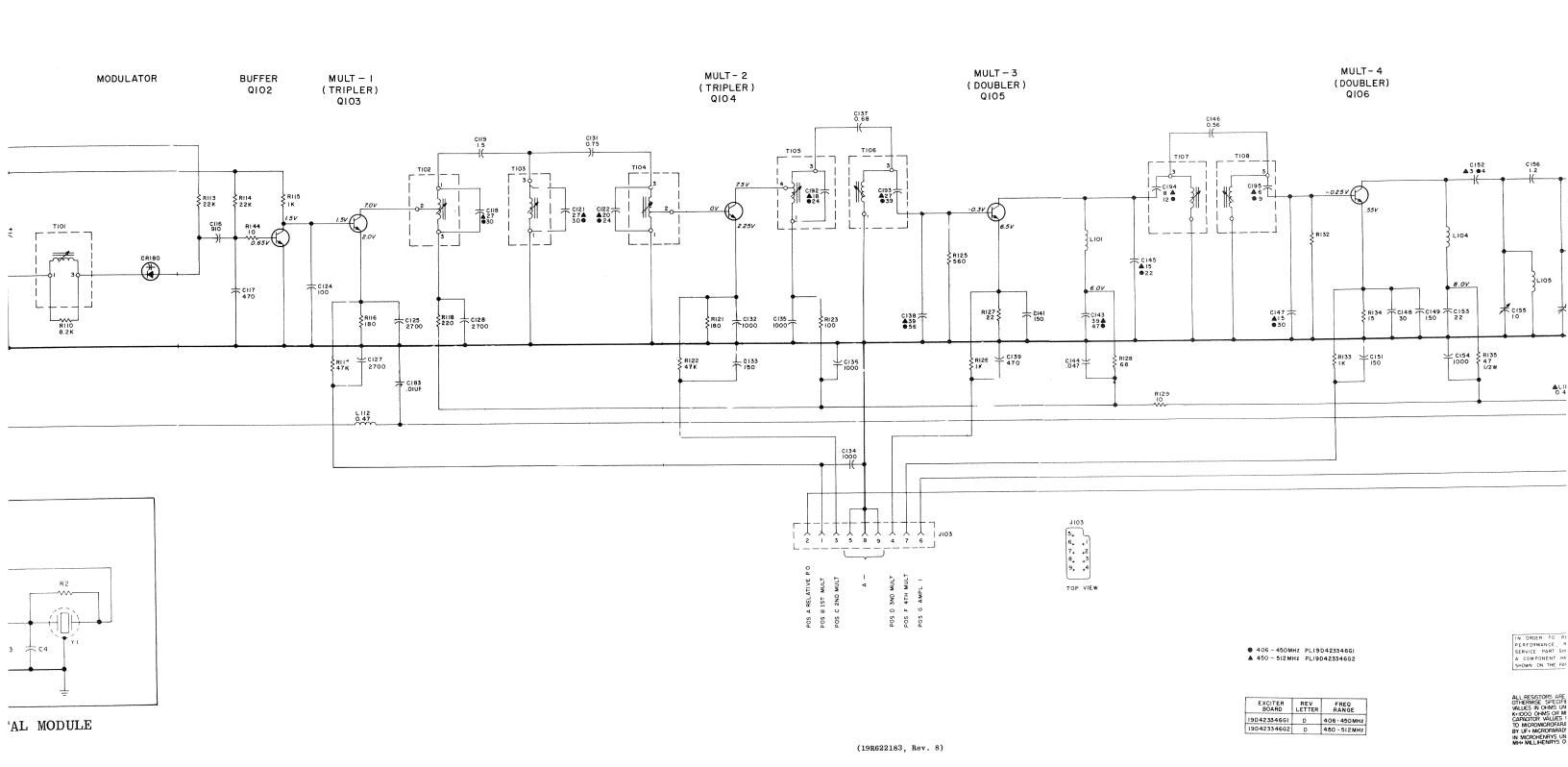
 19D42334662
 D
 450-512MHz

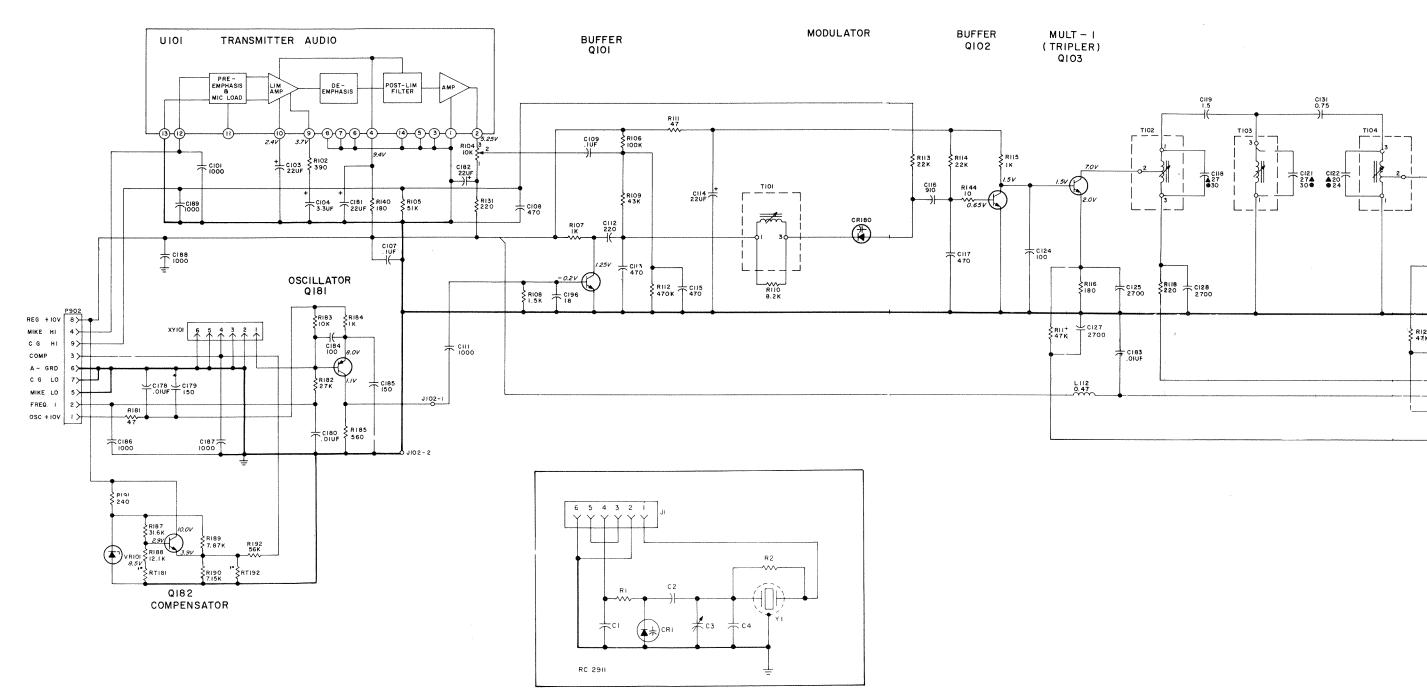
(19R622183, Rev. 8)

ALL RESISTORS ARE 1/4 WATT UNLESS OTHERWISE SPECIFIED AND RESISTOR YALUES IN OHNS UNLESS FOLLOWED BY K-1000 OHNS OR MEG 1,000,000 OHNS OR MEG 1,000,000 OHNS OR MEG 1,000,000 OHNS OR PROPERTY OF A RESISTOR OF A RE

SCHEMATIC DIAGRAM

406—512 MHz EXCITER BOARD 19D423346G1, 2





TYPICAL CRYSTAL MODULE

PARTS LIST

LBI30088D

406-512 MHz EXCITER BOARD 19D423346G1 406-450 MHz 19D423346G2 450-512 MHz

C101	
C101 19A116655P19 Ceramic disc: 1000 pf ±20%, 1000 VDCW; si RMC Type JF Discap. C103 19A134202P5 Tantalum: 22 µf ±20%, 15 VDCW. C104 19A13605P7 Polyester: 0.1 µf ±20%, 50 VDCW. C108 19A116655P19 Ceramic disc: 470 pf ±20%, 1000 VDCW; sim RMC Type JF Discap. C109 19A116655P19 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C112 7489162P35 Silver mica: 220 pf ±5%, 500 VDCW, sim to RMC Type JF Discap. C113 5496372P365 Ceramic disc: 470 pf ±10%, 500 VDCW, temp -4700 PPM. C114 19A134202P6 Tantalum: 22 µf ±20%, 15 VDCW. C115 19A116655P13 Ceramic disc: 470 pf ±10%, 500 VDCW, temp -4700 PPM. C116 5496372P379 Ceramic disc: 470 pf ±10%, 500 VDCW, temp -4700 PPM. C117 5496372P365 Ceramic disc: 470 pf ±10%, 500 VDCW, temp -4700 PPM. C118L 19A116656P30J8 Ceramic disc: 30 pf ±5%, 500 VDCW, temp -680 PPM. C118L 19A116656P30J8 Ceramic disc: 30 pf ±5%, 500 VDCW, temp -680 PPM. C118H 19A116656P27J8 Ceramic disc: 27 pf ±5%, 500 VDCW, temp -680 PPM. C121L 19A116656P27J8 Ceramic disc: 27 pf ±5%, 500 VDCW, temp -680 PPM. C122L 19A116656P27J8 Ceramic disc: 27 pf ±5%, 500 VDCW, temp -680 PPM. C122L 19A116656P27J8 Ceramic disc: 27 pf ±5%, 500 VDCW, temp -680 PPM. C122L 19A116656P27J8 Ceramic disc: 27 pf ±5%, 500 VDCW, temp -680 PPM. C122L 19A116656P27J8 Ceramic disc: 27 pf ±5%, 500 VDCW, temp -680 PPM. C122L 19A116656P27J8 Ceramic disc: 20 pf ±5%, 500 VDCW, temp -680 PPM. C122L 19A116656P27J8 Ceramic disc: 20 pf ±5%, 500 VDCW, temp -680 PPM. C123L 19A116655P21 Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to the Comp -680 PPM. C124 7489162P27 Silver mica: 1000 pf ±20%, 1000 VDCW; sim to MBC Type JF Discap. C125 19A116655P19 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to MBC Type JF Discap. C133 19A116655P19 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to MBC Type JF Discap. C134 19A116655P19 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C136 S49160IP117 Phenolic: 0.68 pf ±5%, 500 VDCW.	************
MMC Type JF Discap. Tantalum: 22 \(\text{pt} \) ±20%, 15 VDCW.	
Tantalum: 3.3 \(\text{ \text{pf}} \) \(\text{torm} \) \(\text{15 VDCW} \) \(\text{16 VDCW} \) \(16 VD	; sim to
Polyester: 0.1 \(\text{pf} \) \(\text{torus} \)	
C108 19A116655P13 Ceramic disc: 470 pf ±20%, 1000 VDCW; sim RMC Type JF Discap. C111 19A116655P19 Polyester: 0.1 µf ±20%, 50 VDCW. C112 7489162P35 Silver mica: 220 pf ±5%, 500 VDCW; sim to RMC Type JF Discap. C113 5496372P365 Ceramic disc: 470 pf ±10%, 500 VDCW; sim to RMC Type JF Discap. C114 19A134202P6 Tantalum: 22 µf ±20%, 15 VDCW. C115 19A116655P13 RMC Type JF Discap. C116 5496372P365 Ceramic disc: 470 pf ±20%, 1000 VDCW; sim RMC Type JF Discap. C117 5496372P365 Ceramic disc: 470 pf ±10%, 500 VDCW, temp -4700 PPM. C118 19A116656P30J8 Ceramic disc: 30 pf ±5%, 500 VDCW, temp -4700 PPM. C118 19A116656P30J8 Ceramic disc: 30 pf ±5%, 500 VDCW, temp condition of the second	
RMC Type JF Discap. Polyester: 0.1 \(\text{pt} \) ±20%, 50 \(\text{PDCW}. \)	
C111 19A116655P19 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C112 7489162P35 Silver mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C113 5496372P365 Ceramic disc: 470 pf ±10%, 500 VDCW, temp-4700 PPM. C114 19A134202P6 Tantalum: 22 µf ±20%, 15 VDCW. C115 19A11665P13 Ceramic disc: 470 pf ±20%, 1000 VDCW; sim RMC Type JF Discap. C116 5496372P379 Ceramic disc: 910 pf ±10%, 500 VDCW, temp-4700 PPM. C117 5496372P365 Ceramic disc: 470 pf ±10%, 500 VDCW, temp-4700 PPM. C118L 19A116656P30JB Ceramic disc: 30 pf ±5%, 500 VDCW, temp-4700 PPM. C119 5491601P123 Phenolic: 1.5 pf ±5%, 500 VDCW, temp-680 PPM. C121L 19A116656P30JB Ceramic disc: 30 pf ±5%, 500 VDCW, temp-680 PPM. C121L 19A116656P30JB Ceramic disc: 30 pf ±5%, 500 VDCW, temp-680 PPM. C122L 19A116656P2JB Ceramic disc: 27 pf ±5%, 500 VDCW, temp-680 PPM. C122L 19A116656P2JB Ceramic disc: 27 pf ±5%, 500 VDCW, temp-680 PPM. C122L 19A116656P2JB Ceramic disc: 24 pf ±5%, 500 VDCW, temp-680 PPM. C122L 19A116656P2JB Ceramic disc: 24 pf ±5%, 500 VDCW, temp-680 PPM. C124 7489162P27 Silver mica: 100 pf ±5%, 500 VDCW; sim temp-880 PPM. C125 19A116655P21 Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C126 19A116655P1 Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C130 19A116655P1 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C131 19A116655P19 Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C132 19A116655P19 Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C134 19A116655P19 Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C136 19A116655P19 Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C137 5491601P117 Ceramic disc: 56 pf ±5%, 500 VDCW.	sim to
Sim to RMC Type JF Discap. C112 7489162P35 Silver mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C113 5496372P365 Ceramic disc: 470 pf ±10%, 500 VDCW, temp-4700 PPM. C114 19A134202P6 Tantalum: 22 µf ±20%, 15 VDCW. C115 19A116655P13 Ceramic disc: 470 pf ±20%, 1000 VDCW; sim RMC Type JF Discap. C116 5496372P365 Ceramic disc: 910 pf ±10%, 500 VDCW, temp-4700 PPM. C117 5496372P365 Ceramic disc: 470 pf ±10%, 500 VDCW, temp-4700 PPM. C118L 19A116656P30J8 Ceramic disc: 30 pf ±5%, 500 VDCW, temp-4700 PPM. C119 5491601P123 Phenolic: 1.5 pf ±5%, 500 VDCW, temp-680 PPM. C121L 19A116656P30J8 Ceramic disc: 27 pf ±5%, 500 VDCW, temp-680 PPM. C121L 19A116656P30J8 Ceramic disc: 30 pf ±5%, 500 VDCW, temp-680 PPM. C122L 19A116656P24J8 Ceramic disc: 27 pf ±5%, 500 VDCW, temp-680 PPM. C122L 19A116656P24J8 Ceramic disc: 27 pf ±5%, 500 VDCW, temp-680 PPM. C122L 19A116656P20J8 Ceramic disc: 24 pf ±5%, 500 VDCW, temp-680 PPM. C122L 19A116656P20J8 Ceramic disc: 24 pf ±5%, 500 VDCW, temp-680 PPM. C124 7489162P27 Silver mica: 100 pf ±5%, 500 VDCW, temp-680 PPM. C125 19A116655P21 Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C127 19A116655P21 Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C130 19A116655P19 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C131 19A116655P19 Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C132 19A116655P19 Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C134 19A116655P19 Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C136 19A116655P19 Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C137 5491601P117 Phenolic: 0.68 pf ±5%, 500 VDCW. Ceramic disc: 56 pf ±5%, 500 VDCW. Ceramic disc: 56 pf ±5%, 500 VDCW, temp-69 PPM.	
Electro Motive Type DM-15. Ceramic disc: 470 pf ±10%, 500 VDCW, temp -4700 PPM. C114	;
-4700 PPM. -4700 PPM. -4701 PPM. -47	m to
C115 19A116655P13 Ceramic disc: 470 pf ±20%, 1000 VDCW; sim RMC Type JF Discap. C116 5496372P379 Ceramic disc: 910 pf ±10%, 500 VDCW, temp -4700 PPM. C117 5496372P365 Ceramic disc: 470 pf ±10%, 500 VDCW, temp -4700 PPM. C118L 19A116656P30J8 Ceramic disc: 30 pf ±5%, 500 VDCW, temp -80 PPM. C118H 19A116656P27J8 Ceramic disc: 27 pf ±5%, 500 VDCW, temp -80 PPM. C119 5491601P123 Phenolic: 1.5 pf ±5%, 500 VDCW, temp -80 PPM. C121L 19A116656P30J8 Ceramic disc: 27 pf ±5%, 500 VDCW, temp -80 PPM. C121H 19A116656P27J8 Ceramic disc: 27 pf ±5%, 500 VDCW, temp -80 PPM. C122L 19A116656P24J8 Ceramic disc: 24 pf ±5%, 500 VDCW, temp -80 PPM. C122H 19A116656P24J8 Ceramic disc: 24 pf ±5%, 500 VDCW, temp -80 PPM. C122H 19A116656P20J8 Ceramic disc: 20 pf ±5%, 500 VDCW, temp -80 PPM. C124 7489162P27 Silver mica: 100 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C125 19A116655P21 Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C131 5491601P118 Phenolic: 0.75 pf ±5%, 500 VDCW. C132 19A116655P19 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C134 19A116655P19 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C135 5491601P17 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C136 5491601P17 Phenolic: 0.68 pf ±5%, 500 VDCW. C138L 19A116655P56J8 Ceramic disc: 56 pf ±5%, 500 VDCW.	temp coef
C116 5496372P379 Ceramic disc: 910 pf ±10%, 500 VDCW, temp -4700 PPM. C117 5496372P365 Ceramic disc: 470 pf ±10%, 500 VDCW, temp -4700 PPM. C118L 19A116656P30J8 Ceramic disc: 30 pf ±5%, 500 VDCW, temp c -80 PPM. C118H 19A116656P27J8 Ceramic disc: 27 pf ±5%, 500 VDCW, temp c -80 PPM. C119 5491601P123 Phenolic: 1.5 pf ±5%, 500 VDCW, temp c -80 PPM. C121L 19A116656P30J8 Ceramic disc: 30 pf ±5%, 500 VDCW, temp c -80 PPM. C121L 19A116656P27J8 Ceramic disc: 30 pf ±5%, 500 VDCW, temp c -80 PPM. C122L 19A116656P24J8 Ceramic disc: 27 pf ±5%, 500 VDCW, temp c -80 PPM. C122L 19A116656P24J8 Ceramic disc: 24 pf ±5%, 500 VDCW, temp c -80 PPM. C122H 19A116656P20J8 Ceramic disc: 20 pf ±5%, 500 VDCW, temp c -80 PPM. C124 7489162P27 Silver mica: 100 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C125 19A116655P21 Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to Type JF Discap. C126 Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C131 5491601P118 Phenolic: 0.75 pf ±5%, 500 VDCW. C132 19A116655P19 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C134 19A116655P19 Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C135 5491601P17 Phenolic: 0.68 pf ±5%, 500 VDCW. C136 5491601P17 Phenolic: 0.68 pf ±5%, 500 VDCW. C137 5491601P17 Phenolic: 0.68 pf ±5%, 500 VDCW.	
C118L	sim to
-4700 PPM. C118L 19A116656P30J8 Ceramic disc: 30 pf ±5%, 500 VDCW, temp of -80 PPM. C119 5491601P123 Phenolic: 1.5 pf ±5%, 500 VDCW, temp of -80 PPM. C121L 19A116656P30J8 Ceramic disc: 30 pf ±5%, 500 VDCW, temp of -80 PPM. C121H 19A116656P27J8 Ceramic disc: 30 pf ±5%, 500 VDCW, temp of -80 PPM. C122L 19A116656P27J8 Ceramic disc: 27 pf ±5%, 500 VDCW, temp of -80 PPM. C122L 19A116656P24J8 Ceramic disc: 24 pf ±5%, 500 VDCW, temp of -80 PPM. C122H 19A116656P20J8 Ceramic disc: 20 pf ±5%, 500 VDCW, temp of -80 PPM. C124 7489162P27 Silver mica: 100 pf ±5%, 500 VDCW, temp of -80 PPM. C125 19A116655P21 Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C127 and c128 Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C131 5491601P118 Phenolic: 0.75 pf ±5%, 500 VDCW. Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C133 19A116655P19 Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C134 thru c136 C137 5491601P117 Phenolic: 0.68 pf ±5%, 500 VDCW. C138L 19A116656P56J8 Ceramic disc: 56 pf ±5%, 500 VDCW, temp -80 PPM.	temp coef
-80 PPM. C118H 19Al16656P27J8 Ceramic disc: 27 pf ±5%, 500 VDCW, temp of -80 PPM. C121L 19Al16656P30J8 Ceramic disc: 30 pf ±5%, 500 VDCW, temp of -80 PPM. C121H 19Al16656P27J8 Ceramic disc: 27 pf ±5%, 500 VDCW, temp of -80 PPM. C122L 19Al16656P24J8 Ceramic disc: 27 pf ±5%, 500 VDCW, temp of -80 PPM. C122H 19Al16656P20J8 Ceramic disc: 24 pf ±5%, 500 VDCW, temp of -80 PPM. C122H 19Al16656P20J8 Ceramic disc: 20 pf ±5%, 500 VDCW, temp of -80 PPM. C124 7489162P27 Silver mica: 100 pf ±5%, 500 VDCW, sim to Electro Motive Type DM-15. C125 19Al16655P21 Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C127 and c128 19Al16655P21 Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C131 5491601P118 Phenolic: 0.75 pf ±5%, 500 VDCW. C132 19Al16655P19 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C133 19Al16655P19 Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C134 thru c136	temp coef
Section Sect	mp coef
C121L 19Al16656P30J8	mp coef
-80 PPM. C121H 19Al16656P27J8 Ceramic disc: 27 pf ±5%, 500 VDCW, temp of -80 PPM. C122L 19Al16656P24J8 Ceramic disc: 24 pf ±5%, 500 VDCW, temp of -80 PPM. C122H 19Al16656P20J8 Ceramic disc: 20 pf ±5%, 500 VDCW, temp of -80 PPM. C124 7489162P27 Silver mica: 100 pf ±5%, 500 VDCW, temp of -80 PPM. C125 19Al16655P21 Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C127 and c128 Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C131 5491601P118 Phenolic: 0.75 pf ±5%, 500 VDCW. C132 19Al16655P19 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C133 19Al16655P19 Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C134 thru c136 5491601P117 Phenolic: 0.68 pf ±5%, 500 VDCW. C137 5491601P117 Phenolic: 0.68 pf ±5%, 500 VDCW. C138L 19Al16656P56J8 Ceramic disc: 56 pf ±5%, 500 VDCW, temp -80 PPM.	
-80 PPM. C122L 19A116656P24J8 Ceramic disc: 24 pf ±5%, 500 VDCW, temp of -80 PPM. C122H 19A116656P20J8 Ceramic disc: 20 pf ±5%, 500 VDCW, temp of -80 PPM. C124 7489162P27 Silver mica: 100 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C125 19A116655P21 Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C127 and c128 Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C131 5491601P118 Phenolic: 0.75 pf ±5%, 500 VDCW. C132 19A116655P19 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C133 19A116655P7 Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C134 thru C136 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C135 5491601P117 Phenolic: 0.68 pf ±5%, 500 VDCW. C136 C137 5491601P117 Phenolic: 0.68 pf ±5%, 500 VDCW, temp -80 PPM.	mp coef
-80 PPM. C122H 19Al16656P20J8 Ceramic disc: 20 pf ±5%, 500 VDCW, temp of -80 PPM. C124 7489162P27 Silver mica: 100 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C125 19Al16655P21 Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C127 and c128 Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C131 5491601P118 Phenolic: 0.75 pf ±5%, 500 VDCW. C132 19Al16655P19 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to Type JF Discap. C133 19Al16655P7 Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C134 thru c136 Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C135 5491601P117 Phenolic: 0.68 pf ±5%, 500 VDCW. C136 C137 5491601P17 Phenolic: 0.68 pf ±5%, 500 VDCW. Ceramic disc: 56 pf ±5%, 500 VDCW, temp -80 PPM.	mp coef
-80 PPM. C124 7489162P27 Silver mica: 100 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C125 19A116655P21 Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C127 and C128 Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C131 5491601P118 Phenolic: 0.75 pf ±5%, 500 VDCW. C132 19A116655P19 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to Type JF Discap. C133 19A116655P7 Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C134 thru C136 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C137 5491601P17 Phenolic: 0.68 pf ±5%, 500 VDCW. C138L 19A116656P56J8 Ceramic disc: 56 pf ±5%, 500 VDCW, temp -80 PPM.	mp coef
Electro Motive Type DM-15. C125	mp coef
C127 and C128 C131 C131 C132 C132 C133 C133 C134 C134 C134 C134 C135 C136 C137 C137 C138L C138L C138 C138 C138 C139 C	m to
sim to RMC Type JF Discap. C131 5491601P118 Phenolic: 0.75 pf ±5%, 500 vDCW. C132 19A116655P19 Ceramic disc: 1000 pf ±20%, 1000 vDCW; s. RMC Type JF Discap. C133 19A116655P7 Ceramic disc: 150 pf ±20%, 1000 vDCW; six RMC Type JF Discap. C134 thru C136 C137 5491601P117 Phenolic: 0.68 pf ±5%, 500 vDCW. C138L 19A116656P56J8 Ceramic disc: 56 pf ±5%, 500 vDCW, temp -80 PPM.	; sim to
C131 5491601P118 Phenolic: 0.75 pf ±5%, 500 VDCW. C132 19A116655P19 Ceramic disc: 1000 pf ±20%, 1000 VDCW; s. RMC Type JF Discap. C133 19A116655P7 Ceramic disc: 150 pf ±20%, 1000 VDCW; six RMC Type JF Discap. C134 thru C136 C137 5491601P117 Phenolic: 0.68 pf ±5%, 500 VDCW. C138L 19A116656P56J8 Ceramic disc: 56 pf ±5%, 500 VDCW, temp -80 PPM.	1;
C132 19A116655P19 Ceramic disc: 1000 pf ±20%, 1000 vDCW; s. RMC Type JF Discap. C133 19A116655P7 Ceramic disc: 150 pf ±20%, 1000 vDCW; six RMC Type JF Discap. C134 thru C136 C137 5491601P117 Phenolic: 0.68 pf ±5%, 500 vDCW. C138L 19A116656P56J8 Ceramic disc: 56 pf ±5%, 500 vDCW, temp -80 PPM.	
C134 thru c136	i; sim to
thru C136 sim to RMC Type JF Discap. C137 5491601P117 Phenolic: 0.68 pf ±5%, 500 VDCW. C138L 19Al16656P56J8 Ceramic disc: 56 pf ±5%, 500 VDCW, temp -80 PPM.	; sim to
C137 5491601P117 Phenolic: 0.68 pf ±5%, 500 VDCW. C138L 19Al16656P56J8 Ceramic disc: 56 pf ±5%, 500 VDCW, temp -80 PPM.	й;
Cl38L 19All6656P56J8 Ceramic disc: 56 pf ±5%, 500 VDCW, temp -80 PPM.	
	emp coef
Cl38H 19All6656P39J8 Ceramic disc: 39 pf ±5%, 500 VDCW, temp -80 PPM.	emp coef
C139 19A116655P13 Ceramic disc: 470 pf ±20%, 1000 VDCW; si	; sim to
C141 19A116655P7 Ceramic disc: 150 pf ±20%, 1000 VDCW; si	; sim to

SYMBOL	GE PART NO.	DESCRIPTION	S
C143L	7489162P19	Silver mica: 47 pf ±5%, 500 VDCW; sim to	Cl
С143Н	7489162P17	Electro Motive Type DM-15. Silver mica: 39 pf ±5%, 500 VDCW; sim to	Cl
63.44	19Al16080P5	Electro Motive Type DM-15. Polyester: 0.047 µf ±20%, 50 VDCW.	
C144 C145L	19A116656P22J8	Ceramic disc: 22 pf ±5%, 500 VDCW, temp coef	th Cl
C145H	19All6656Pl5J8	-80 PPM. Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef -80 PPM.	C1
C146	5491601P115	Phenolic: 0.56 pf ±5%, 500 VDCW.	C1
C147L	19A116656P30J8	Ceramic disc: 30 pf ±5%, 500 VDCW, temp coef -80 PPM.	Cl
С147Н	19A116656P15J8	Ceramic disc: 39 pf ±5%, 500 VDCW, temp coef -80 PPM.	C1
C148	19All6656P30J8	Ceramic disc: 30 pf ±5%, 500 VDCW, temp coef -80 PPM.	C1
C149	19Al16655P7	Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	Cl
C151	19A116655P7	Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	cı
C152L	19Al16656P4J0	Ceramic disc: 4 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.	C1
C152H	19A116656P3J0	Ceramic disc: 3 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.	Cl
C153	7489162P11	Silver mica: 22 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C1
C154	19Al16655Pl9	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	C1
C155	19B209544P2	Variable, air: 2.04 to 9.9 pf; sim to EF Johnson Type T187.	
C156*	5491601Pl22	Phenolic: 1.2 pf ±5%, 500 VDCW.	CF
		In REV B and earlier:	CF
C157	5491601P120 19B209544P2	Phenolic: 1.0 pf ±5%, 500 VDCW. Variable, air: 2.04 to 9.9 pf; sim to EF Johnson	
C157		Type T187. Ceramic disc: 6 pf 0.5 pf, 500 VDCW, temp coef	J
C161L	19A116656P6J8	-80 PPM.	J:
C161H	19A116656P5J8	Ceramic disc: 5 pf ±0.5 pf, 500 VDCW, temp coef -80 PPM.	J
C162	19A116656P47J1	Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef -150 PPM.	
C163	19A116656P30J8	Ceramic disc: 30 pf ±5%, 500 VDCW, temp coef -80 PPM.	L
C164	19A116655P7	Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	L
C165	7489162P9	Silver mica: 18 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	L
C166L	19A116656P4J0	Ceramic disc: 4 pf 0.5 pf, 500 VDCW, temp coef 0 PPM.	L
C166H	19A116656P3J0	Ceramic disc: 3 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.	L
C167	19B209544P2	Variable, air: 2.04 to 9.9 pf; sim to EF Johnson Type T187.	I
C168	19A116656P47J1	Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef	
C171	19B209544P2	Variable, air: 2.04 to 9.9 pf; sim to EF Johnson Type T187.	
C172	19Al16080P7	Polyester: 0.1 μf ±20%, 50 VDCW.	
C175	19B209544P2	Variable, air: 2.04 to 9.9 pf; sim to EF Johnson Type T187.	I
C176	19A116655P19	Ceramic disc: 1000 pf $\pm 20\%$, 1000 VDCW; sim to RMC Type JF Discap.	
C177	19A134202P6	Tantalum: 22 μf ±20%, 15 VDCW.]]
C178	19Al16080Pl	Polyester: 0.01 µf ±20%, 50 VDCW.	
C179	19A116655P7	Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	
C180	19A116080Pl	Polyester: 0.01 µf ±20%, 50 VDCW.	
C181 and C182	19A134202P6	Tantalum: 22 μf ±20%, 15 VDCW.	
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SYMBOL	GE PART NO.	DESCRIPTION
C183	19A116080P1	Polyester: 0.01 μf ±20%, 50 VDCW.
C184	19All6656Pl00J7	Ceramic disc: 100 pf ±5%, 500 VDCW, temp coef -750 PPM.
C185	7489162P31	Silver mica: 150 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C186 thru C189	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C190	5491601P120	Phenolic: 1.0 pf ±5%, 500 VDCW.
0191	19A116655P7	Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C192L	19All6656P24J8	Ceramic disc: 24 pf ±5%, 500 VDCW, temp coef -80 PPM.
С192Н	19Al16656P18J8	Ceramic disc: 8 pf ±5%, 500 VDCW, temp coef -80 PPM.
C193L	19A116656P39J8	Ceramic disc: 39 pf ±5%, 500 VDCW, temp coef -80 PPM.
С193Н	19A116656P27J8	Ceramic disc: 27 pf ±5%, 500 YDCW, temp coef -80 PPM.
C194L	19A116656P12J8	Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef -80 PPM.
C194H	19A116656P8J8	Ceramic disc: 8 pf ±0.5 pf, 500 VDCW, temp coef -80 PPM.
C195L	19A116656P9J8	Ceramic disc: 9 pf ± 0.5 pf, 500 VDCW, temp coef -80 PPM.
С195Н	19A116656P6J8	Ceramic disc: 6 pf ±0.5 pf, 500 VDCW, temp coef -80 PPM.
C196*	7489162P109	Silver mica: 18 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15. Added by REV A.
		DIODES AND RECTIFIERS
CR180	5495769P8	Diode, silicon.
CR181	19A116052P2	Silicon.
		JACKS AND RECEPTACLES
J101	19A130924G1	Connector, receptacle: jack type; sim to Cinch 14H11613.
J102	19A116779P1	Contact, electrical: sim to Molex 08-50-0404. (Quantity 2).
J103	19B219374G1	Connector: 9 contacts.
L101	19A130255P3	Coil.
L104	19A130255P2	Coil.
L105	19A130443P1	Coil.
L106L	19A130443P4	Coil.
L106H	19A130443P2	Coil.
L107	19A130255P2	Coil.
L108	19A130443P1	Coll.
L109	19A130443P3	Coil.
L111	19B209420P103	Coil, RF: 0.15 μh $\pm 10\%,$ 0.10 ohms DC res max; sim to Jeffers 4416-3K.
L112	19B209420P109	Coil, RF: 0.47 μh $\pm 10\%,$ 0.34 ohms DC res max; sim to Jeffers 4426-2K.
L113	19B209420Pl	Coil, RF: 0.10 µh ±5%, 0.08 ohms DC res max; sim to Jeffers 4412-1J.
L114	19B209420P109	Coil, RF: 0.47 µh ±10%, 0.34 ohms DC res max; sim to Jeffers 4426-2K.
		PLUGS
P101	19All6659P2	Connector, printed wiring: 10 contacts; sim to Molex 09-52-3102.
Q101	19A115910Pl	Silicon, NPN; sim to Type 2N3904.
Q102	19A115330Pl	Silicon, NPN.
Q103	19A115328Pl	Silicon, NPN.
Q104*	19A116899Pl	Silicon, NPN: sim to Type 2N2368.
		In REV C and earlier:
	1	Silicon, NPN.
	19A115328Pl	L DARACOM, MANY

SYMBOL	GE PART NO.	DESCRIPTION
R186	3R152P332K	Composition: 3.3K ohms ±10%, 1/4 w.
R187	19C314256P23162	Metal film: 31.60K ohms $\pm 1\%$, $1/4$ w.
R188	19C314256P21212	Metal film: 12.10K ohms $\pm1\%$, 1/4 w.
R189	19C314256P27871	Metal film: 7.87K ohms $\pm 1\%$, $1/4$ w.
R190	19C314256P27151	Metal film: 7.15K ohms $\pm 1\%$, $1/4$ w.
R191	3R152P241J	Composition: 240 ohms $\pm 5\%$, $1/4$ w.
R192	3R152P563K	Composition: 56K ohms ±10%, 1/4 w.
		THERMISTORS
RT181	19C300048P7	Disc: 5K ohms ±10%; sim to NL Ind. 1D103.
RT182	19C300048P15	Disc: 200K ohms ±10%; sim to NL Ind. 4D0514.
		TRANSFORMERS
T101	19C307171P101	Coil, RF.
T102	19C307170P305	Coil, RF.
T103	19C307170P306	Coil, RF.
T104	19C307170P307	Coil, RF.
T105	19C307169P202	Coil, RF.
Т106	19C307169P203	Coil, RF.
T107 and	19C307169P204	Coil, RF.
T108		INTEGRATED CIRCUITS
U101	19D416542G2	Transmitter, Audio.
		VOLTAGE REGULATORS
VR101	4036887P9	Silicon, Zener.
		SOCKETS
XY101*		Connector, Includes:
	19A116779Pl	Contact, electrical: sim to Molex 08-50-040
	19C327251Pl	Clip.
		Earlier than REV A:
	19A116659P50	Connector, printed wiring: 6 contacts; sim Molex 09-65-1061.
		CRYSTAL MODULES
		NOTE: When reordering, give GE Part Number specify exact operating frequency needed.
Y101	198226962G6	Crystal module: 5 PPM, 406-420 MHz.
	198226962G7	Crystal module: 5 PPM, 450-470 MHz.
	19B226962G8	Crystal module: 5 PPM, 470-494 MHz.
:	19B226962G9	Crystal module: 5 PPM, 494-512 MHz.
		MISCELLANEOUS
	19A129424G2	Can. (Used with T101-T108).
	19C321695G1	Shield.
	19A116707P3	Insulator, disc: sim to Thermalloy 7717-46. (Used with Q105-Q107).
	1903216950	1
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GE PART NO.	DESCRIPTION
19Al16080Pl	Polyester: 0.01 µf ±20%, 50 VDCW.
19Al16656Pl00J7	Ceramic disc: 100 pf ±5%, 500 VDCW, temp coef -750 PPM.
7489162P31	Silver mica: 150 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
19Al16655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
5491601P120	Phenolic: 1.0 pf ±5%, 500 VDCW.
19A116655P7	Ceramic disc: 150 pf ±20%, 1000 VDCW;
19A116656P24J8	sim to RMC Type JF Discap. Ceramic disc: 24 pf ±5%, 500 VDCW, temp coef
19A116656P18J8	-80 PPM. Ceramic disc: 8 pf ±5%, 500 VDCW, temp coef
19A116656P39J8	-80 PPM. Ceramic disc: 39 pf ±5%, 500 VDCW, temp coef
	-80 PPM.
19A116656P27J8	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef -80 PPM.
19A116656P12J8	Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef -80 PPM.
19Al16656P8J8	Ceramic disc: 8 pf ±0.5 pf, 500 VDCW, temp coef -80 PPM.
19A116656P9J8	Ceramic disc: 9 pf ±0.5 pf, 500 VDCW, temp coef -80 PPM.
19A116656P6J8	Ceramic disc: 6 pf ±0.5 pf, 500 VDCW, temp coef -80 PPM.
7489162P109	Silver mica: 18 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15. Added by REV A.
	DIODES AND RECTIFIERS
5495769P8	Diode, silicon.
19Al16052P2	Silicon.
	JACKS AND RECEPTACLES
19A130924G1	Connector, receptacle: jack type; sim to Cinch 14H11613.
19A116779P1	Contact, electrical: sim to Molex 08-50-0404. (Quantity 2).
19B219374G1	Connector: 9 contacts.
	INDUCTORS
19A130255P3	Coil.
19A130255P2	Coil.
19A130443P1	Coil.
19A130443P4	Coil.
19A130443P2	Coil.
19A130255P2	Coil.
19A130443Pl	Coil.
19A130443P3	Coil.
19B209420P103	Coil, RF: 0.15 μh $\pm 10\%$, 0.10 ohms DC res max; sim to Jeffers 4416-3K.
19B209420P109	Coil, RF: 0.47 µh ±10%, 0.34 ohms DC res max; sim to Jeffers 4426-2K.
19B209420P1	Coil, RF: 0.10 µh ±5%, 0.08 ohms DC res max; sim to Jeffers 4412-1J.
19B209420P109	Coil, RF: 0.47 μh $\pm 10\%$, 0.34 ohms DC res max; sim to Jeffers 4426-2K.
	PLUGS
19A116659P2	Connector, printed wiring: 10 contacts; sim to
	Molex 09-52-3102.
19A115910P1	Silicon, NPN; sim to Type 2N3904.
19A115330P1	Silicon, NPN.
19A115328P1	Silicon, NPW.
19A116899Pl	Silicon, NPN: sim to Type 2N2368. In REV C and earlier:
19A115328P1	Silicon, NPN.
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SYMBOL	GE PART NO.	DESCRIPTION
R186	3R152P332K	Composition: 3.3K ohms ±10%, 1/4 w.
R187	19C314256P23162	Metal film: 31.60K ohms ±1%, 1/4 w.
R188	19C314256P21212	Metal film: 12.10K ohms ±1%, 1/4 w.
R189	19C314256P27871	Metal film: $7.87K$ ohms $\pm 1\%$, $1/4$ w.
R190	19C314256P27151	Metal film: 7.15K ohms $\pm 1\%$, $1/4$ w.
R191	3R152P241J	Composition: 240 ohms ±5%, 1/4 w.
R192	3R152P563K	Composition: 56K ohms ±10%, 1/4 w.
		THERMISTORS
RT181	19C300048P7	Disc: 5K ohms ±10%; sim to NL Ind. 1D103.
RT182	19C300048P15	Disc: 200K ohms $\pm 10\%$; sim to NL Ind. 4D0514.
T101	19C307171P101	Coil, RF.
T102	19C307170P305	Coil, RF.
T103	19C307170P306	Coil, RF.
T104	19C307170P307	Coil, RF.
T105	19C307169P202	Coil, RF.
T106	19C307169P203	Coil, RF.
T107	19C307169P204	Coil, RF.
and T108	190307105P204	corr, m.
:		INTEGRATED CIRCUITS
U101	19D416542G2	Transmitter, Audio.
		VOLTAGE REGULATORS
VR101	4036887P9	Silicon, Zener.
		SOCKETS
XY101*		Connector, Includes:
	19Al16779Pl	Contact, electrical: sim to Molex 08-50-0404.
	19C327251Pl	Clip.
		Earlier than REV A:
	19A116659P50	Connector, printed wiring: 6 contacts; sim to Molex 09-65-1061.
		CRYSTAL MODULES
		NOTE: When reordering, give GE Part Number and specify exact operating frequency needed.
Y101	19B226962G6	Crystal module: 5 PPM, 406-420 MHz.
-	19B226962G7	Crystal module: 5 PPM, 450-470 MHz.
	19B226962G8	Crystal module: 5 PPM, 470-494 MHz.
	19B226962G9	Crystal module: 5 PPM, 494-512 MHz.
	13022030203	
		MISCELLANEOUS
	19A129424G2	Can. (Used with T101-T108).
	19C321695G1	Shield.
	19A116707P3	Insulator, disc: sim to Thermalloy 7717-46.
		(Used with Q105-Q107).

	SYMBOL	GE PART NO.	DESCRIPTION
	Q105 and Q106	19All6201201P3	Silicon, NPN.
١	Q107*	19Al16201P4	Silicon, NPN.
			In REV A and earlier:
١		19A116201P1	Silicon, NPN.
	Q181	19A115852P1	Silicon, PNP; sim to Type 2N3906.
	Q182	19Al16774Pl	Silicon, NPN; sim to Type 2N5210.
١			RESISTORS
١	R102	3R152P391K	Composition: 390 ohms $\pm 10\%$, $1/4$ w.
	R104	19B209358P106	Variable, carbon film: approx 300 to 10K ohms ±10%, 0.25 w; sim to CTS Type X-201.
	R105	3R152P512J	Composition: 5.1K ohms ±5%, 1/4 w.
	R106	3R152P104K	Composition: 0.10 megohm ±10%, 1/4 w.
	R107	3R152P102K	Composition: 1K ohms ±10%, 1/4 w.
	R108	3R152P152K	Composition: 1.5K ohms ±10%, 1/4 w.
	R109	3R152P443J	Composition: 44K ohms ±5%, 1/4 w.
	R110	3R152P822J	Composition: 8.2K ohms ±5%, 1/4 w.
	R111	3R152P470J	Composition: 47 ohms ±5%, 1/4 w.
	R112	3R152P474J	Composition: 0.47 megohm ±5%, 1/4 w.
	R113 and R114	3R152P223J	Composition: 22K ohms ±5%, 1/4 w.
	R115	3R152P102K	Composition: 1K ohms ±10%, 1/4 w.
	R116	3R152P181K	Composition: 180 ohms $\pm 10\%$, 1/4 w.
	R117	3R152P473K	Composition: 47K ohms ±10%, 1/4 w.
	R118	3R152P221J	Composition: 220 ohms ±5%, 1/4 w.
	R121*	3R152P181K	Composition: 180 ohms $\pm 10\%$, 1/4 w.
			In REV B and earlier:
		3R152P151K	Composition: 150 ohms ±10%, 1/4 w.
	R122	3R152P473K	Composition: 47K ohms ±10%, 1/4 w.
i	R123	3R152P101K	Composition: 100 ohms ±10%, 1/4 w.
	R125	3R152P561K	Composition: 560 ohms ±10%, 1/4 w.
	R126	3R152P102K	Composition: 1K ohms ±10%, 1/4 w.
	R127	19A116310P39	Composition: 22 ohms ±5%, 0.25 w; sim to Allen-Bradley Type CB.
	R128	3R152P680K	Composition: 68 ohms ±10%, 1/4 w.
	R129	3R152P100K	Composition: 10 ohms ±10%, 1/4 w.
	R131	3R152P221J	Composition: 220 ohms ±5%, 1/4 w.
	R132	3R152P331J	Composition: 330 ohms ±5%, 1/4 w.
	R133	3R152P102K	Composition: 1K ohms ±10%, 1/4 w.
	R134	19A116310P37	Composition: 15 ohms ±5%, 0.25 w; sim to Allen-Bradley Type CB.
1	R135	3R77P470K	Composition: 47 ohms $\pm 10\%$, $1/2$ w.
	R136	3R152P100K	Composition: 10 ohms ±10%, 1/4 w.
	R137	3R152P222K	Composition: 2.2K ohms ±10%, 1/4 w.
	R138	3R152P101K	Composition: 100 ohms ±10%, 1/4 w.
	R139	19A116310P35	Composition: 10 ohms ±5%, 0.25 w; sim to Allen-Bradley Type CB.
	R140	3R152P181K	Composition: 180 ohms $\pm 10\%$, $1/4$ w.
	R141	3R77P470K	Composition: 47 ohms ±10%, 1/2 w.
	R142	3R152P102K	Composition: 1K ohms ±10%, 1/4 w.
	R144	3R152P100K	Composition: 10 ohms ±10%, 1/4 w.
	R181	3R152P470J	Composition: 47 ohms ±5%, 1/4 w.
	R182	3R152P273K	Composition: 27K ohms ±10%, 1/4 w. Composition: 10K ohms ±10%, 1/4 w.
	R183	3R152P103K	
	R184	3R152P102K	
	R185	3R152P561K	Composition: 560 ohms ±10%, 1/4 w.
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PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

- REV. A To permit use with Custom MVP radios. Changed XY101 and added C196.
- REV. B To improve power output. Changed Q107.
- REV. C To improve power output at 512 MHz. Changed C156 and R121.
- REV. D To incorporate new transistor. Changed Q104.